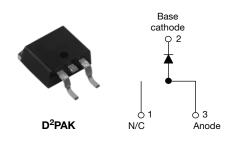


**Vishay High Power Products** 

## Schottky Rectifier, 7.5 A



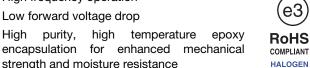
PRODUCT SUMMARY			
I <sub>F(AV)</sub> 7.5 A			
V <sub>R</sub> 35 V/45 V			
I <sub>RM</sub> 15 mA at 125 °C			

## **FEATURES**

• High purity,

- 150 °C T<sub>J</sub> operation
- · High frequency operation
- Low forward voltage drop

strength and moisture resistance



FREE

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified

## DESCRIPTION

The VS-MBRB7... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	BOL CHARACTERISTICS VALUES		UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	7.5	А		
V <sub>RRM</sub>		35/45	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	690	А		
V <sub>F</sub>	7.5 Apk, T <sub>J</sub> = 125 °C	0.57	V		
TJ	Range	- 65 to 150	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-MBRB735PbF	VS-MBRB745PbF	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	35	45	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>		45	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	$T_{C}$ = 131 °C, rated $V_{R}$		7.5	
Non-repetitive peak surge current	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	690	А
		Surge applied at rated load c	ondition halfwave single phase 60 Hz	150	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 3.5 mH		7	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		2	A

# VS-MBRB735PbF, VS-MBRB745PbF

Vishay High Power Products Schottky Rectifier, 7.5 A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		15 A	T <sub>J</sub> = 25 °C	0.84	
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	7.5 A	- T <sub>J</sub> = 125 °C -	0.57	V
		15 A		0.72	
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.1	mA
Waximum instantaneous reverse current		T <sub>J</sub> = 125 °C		15	
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C 400		400	pF
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane 8.0 r		nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/μs		V/µs	

#### Note

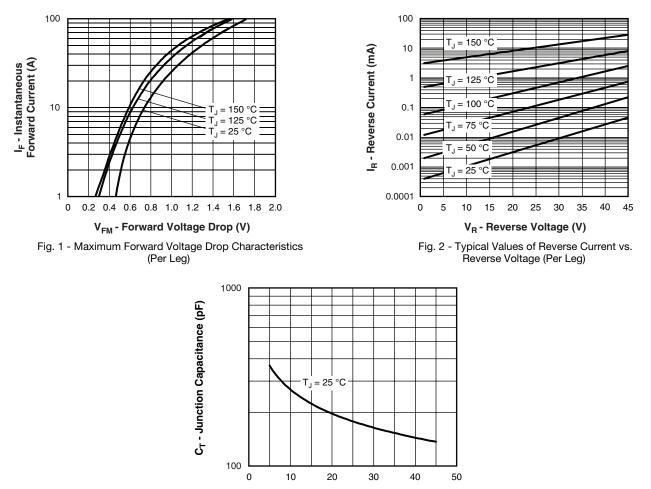
 $^{(1)}\,$  Pulse width < 300  $\mu s,\,duty\,cycle$  < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range		TJ		- 65 to 150	50 °C	
Maximum storage temperature range		T <sub>Stg</sub>		- 65 to 175	U	
Junction to case		R <sub>thJC</sub>	DC operation	3.0	- °C/W	
		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
				0.07	oz.	
Mounting torque minimum maximum				6 (5)	kgf ⋅ cm	
				12 (10)	(lbf · in)	
Marking device			Case style D <sup>2</sup> PAK	MBR	MBRB735	
			Case signe D-FAR	MBR	MBRB745	



## VS-MBRB735PbF, VS-MBRB745PbF

Schottky Rectifier, 7.5 A Vishay High Power Products



V<sub>R</sub> - Reverse Voltage (V)

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

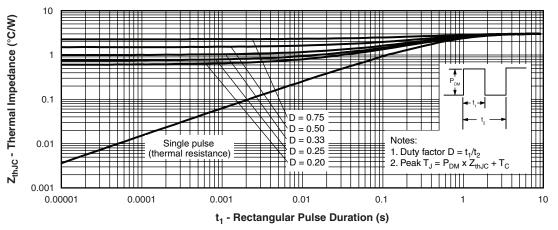
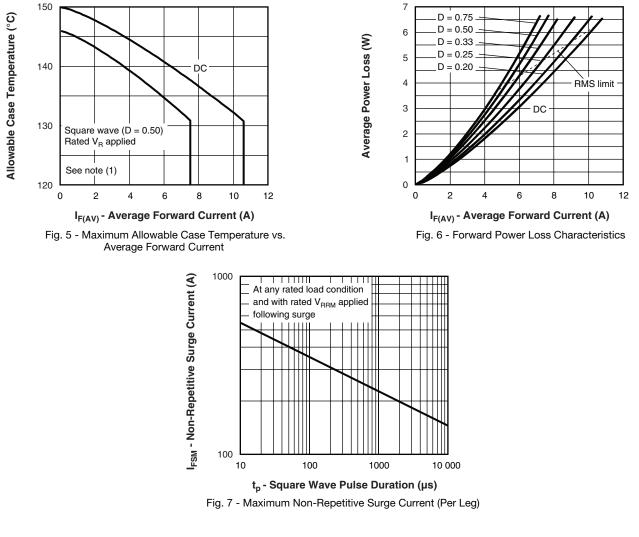


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

# VS-MBRB735PbF, VS-MBRB745PbF

Vishay High Power Products

Schottky Rectifier, 7.5 A



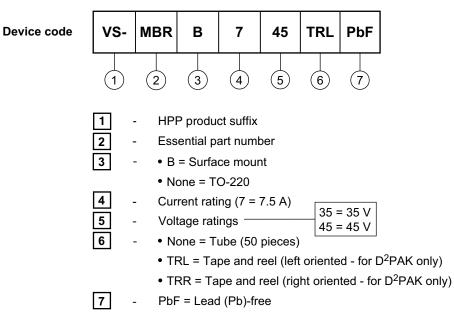
#### Note

- (1) Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{th,JC};$   $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 D); I_R at V_{R1} = Rated V_R$



Schottky Rectifier, 7.5 A Vishay High Power Products

### **ORDERING INFORMATION TABLE**



LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95046</u>				
Part marking information <u>www.vishay.com/doc?95054</u>				
Packaging information <u>www.vishay.com/doc?95032</u>				
SPICE model	www.vishay.com/doc?95298			



Vishay

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